

Transponder Interface for Microcontroller

General Description

The U3280M IC is a transponder interface which enables contactless ID systems, remote control systems, tag and sensor applications. It is able to supply a microcontroller with power from an RF field via a LC-resonant circuit and it enables the controller for contactless bidirectional data

communication via this RF field. It includes a power management which handles switching between magnetic field and battery power supply. To store permanent data like identifiercode and configuration data the U3280M includes a 512-bit EEPROM with an serial interface .

Features

- Contactless power supply and communication interface
- Up to 10 kbaud data rate (R/O)
- Power management for contactless- and battery power supply
- Frequency range 100 to 150 kHz
- 32 x 16-bit EEPROM
- Two wire serial interface
- Shift register supported Biphase and Manchester modulator stage
- Reset I/O line
- Field clock extractor
- Field and gap detection output for wake up and data reception

- Field modulator with energy-saving damping stage

Applications

- Overview
 - Access control
 - Telemetry
 - Wireless sensors

Par example:

- Wireless passive access and active alarm control for protection of valuables
- Contactless position sensors for alignments of machines
- Contactless status verification and/ or data readout from sensors

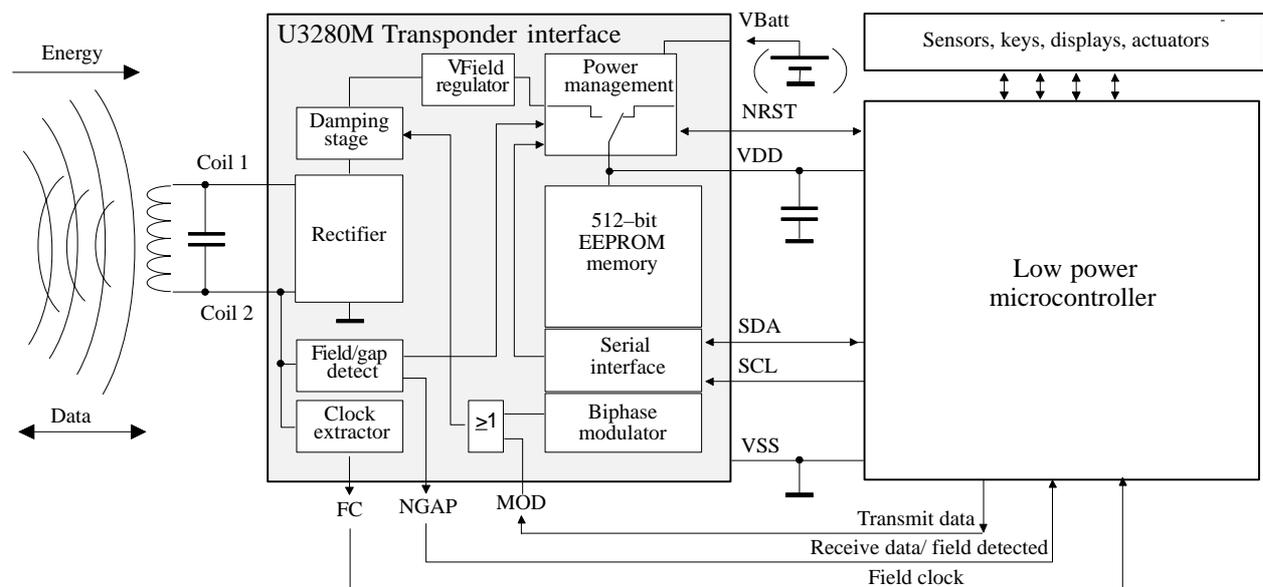


Figure 1. Block Diagram

Ordering Information

U3280M-MFB	SSO16	Tube
U3280M-MFBG3	SSO16	Taped and reeled

Pin Description

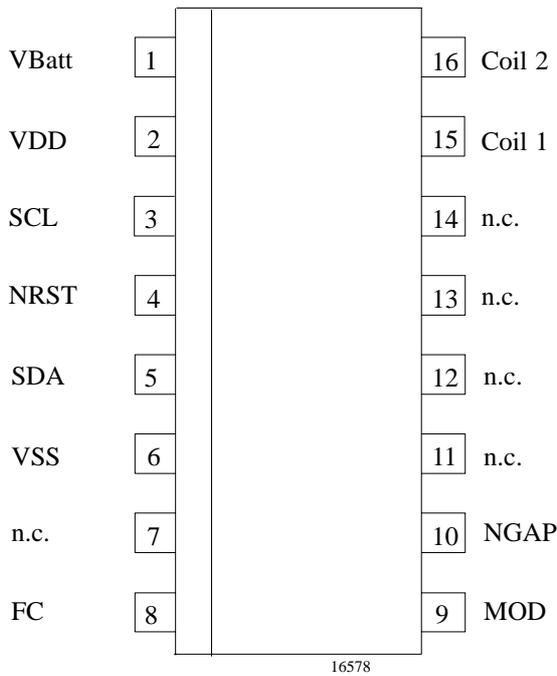


Figure 2. Pinning

Pin	Symbol	Function
1	V _{Batt}	Power supply voltage input to connect a battery
2	V _{DD}	Power supply voltage for the μ C and EEPROM. At this pin a buffer capacitor (0.5... 10 μ F) must be connected to buffer the voltage during field supply and to block the VDD of the μ C.
3	SCL	Serial clock line
4	NRST	Reset line bidirectional
5	SDA	Serial data line
6	V _{SS}	Circuit ground
7	n.c.	Not connected
8	FC	Field clock output of the front end clock extractor
9	MOD	Modulation input
10	NGAP	Gap and field detect output
15	Coil 1	Coil input 1. Pin to connect a resonant circuitry for communication and field supply
16	Coil 2	Coil input 2, see above

1 Functional Description

1.1 The Transponder Interface

The U3280M is a transponder interface IC which is able to operate microcontrollers wireless and battery-independent. Wireless data communication and power supply are handled via an electromagnetic field and the coil antenna of the transponder interface. The U3280M consists of a rectifier stage for the antenna, a power management to handle field and battery power supply, a damping modulator and a field-gap detection stage for contactless data communication, further a field clock extraction and an EEPROM are on the chip.

The internal rectifier stage rectifies the AC from the LC-resonant circuit at the coil inputs and supplies the U3280M device and an additional microcontroller device with power. It is also possible to supply the device via the VBatt input with DC from a battery. The power management handles switching between battery supply (VBatt pin) and field supply automatically. It switches to field supply if a field is applied at the coil and it switches back to battery if the field is removed. The voltage from the coil or the VBatt pin is output at the VDD pin to supply the microcontroller or any other suited device. At the VDD pin a capacitor must be connected to smooth and buffer the supply voltage. This capacitor is also necessary to buffer the supply voltage during the communication (damping and gaps in the field).

For communication, the chip contains a damping stage and a gap-detect circuitry. By means of the damping stage the coil voltage can be modulated to transmit data via the field. It can be controlled with the modulator input (MOD pin) via the microcontroller. The gap-detection circuitry detects gaps in the field and outputs the gap/field signal at the gap-detect output (Pin NGAP).

For the storage of data like keycodes, identifiers and configuration bits a 512-bit EEPROM is available on the chip. It can be read and written by the microcontroller via an I²C compatible two-wire serial interface.

The serial interface, the EEPROM and the microcontroller are supplied with the voltage at the VDD pin. That means the microcontroller can read and write the EEPROM if the supply voltage at VDD is in the operating range of the IC.

The U3280M has build in operating modes to support a wide range of applications. These modes can be activated via the serial interface with special mode control bytes.

To support applications with battery supply only, the power management can be switched off by software to disable the automatic switching to field supply.

An on-chip Biphase and Manchester modulator can be activated and controlled by the serial interface. If this modulator is used it modulates the serial data stream at the serial inputs SDA and SCL into a Biphase or Manchester coded signal for the damping stage.

1.2 Modulation

The transponder interface can modulate the magnetic field by its damping stage to transmit data to a base station. It modulates the coil voltage by varying the coil's load. The modulator can be controlled via the MOD pin. A high level ("1") increases the current into the coil and damps the coil voltage. A low level ("0") decreases the current and increases the coil voltage. The modulator generates a voltage stroke of about $2 V_{pp}$ at the coil. A high level at the MOD pin makes the maximum of the field energy available at VDD. During a reset a high level at the MOD pin causes the optimum conditions for starting the device and charging the capacitor at VDD after the field is applied at the coil.

Digital input to control the damping stage (MOD)

MOD = 0: coil not damped

$$V_{\text{coil_peak}} = VDD \times \sqrt{2} + V_{\text{CMS}} = V_{\text{CU}}$$

MOD = 1: coil damped

$$V_{\text{coil_peak}} = VDD \times \sqrt{2} = V_{\text{CD}}$$

$V_{\text{CMS}} = V_{\text{CID}}$: modulation voltage stroke @ coil inputs

Note: If the automatic power management is disabled, the internal front end V_{DD} is limited at V_{DDC}. In this case the value V_{DDC} must be used in the above formula.

1.3 Field clock

The field clock extractor of the interface makes the field clock available for the microcontroller. It can be used to supply timer inputs to synchronize modulation and demodulation with the field clock.

1.4 Gap Detect

The transponder interface can also receive data. The base station modulates the data with short gaps in the field. The gap-detection circuit detects these gaps in the magnetic field and outputs the NGAP/field signal at the NGAP pin. A high level indicates that a field is applied at the coil and a low level indicates a gap or that the field is off. The microcontroller must demodulate the incoming data stream at one of its inputs.

1.5 U3280M Signals and Timing

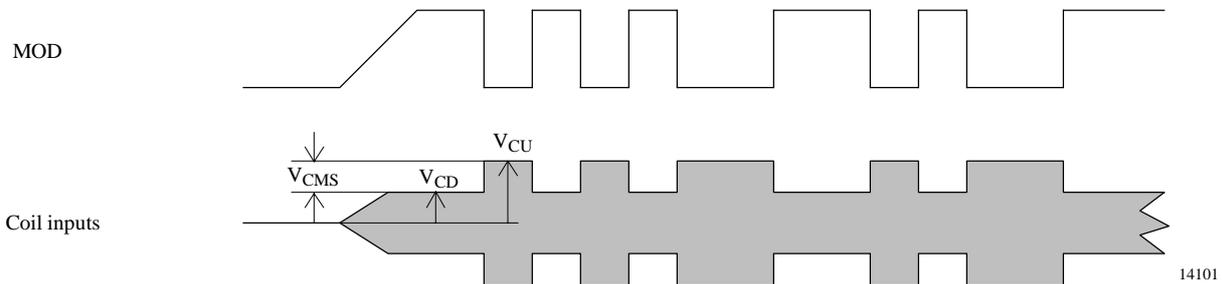


Figure 3. Modulation

Gap detection and battery to field switching

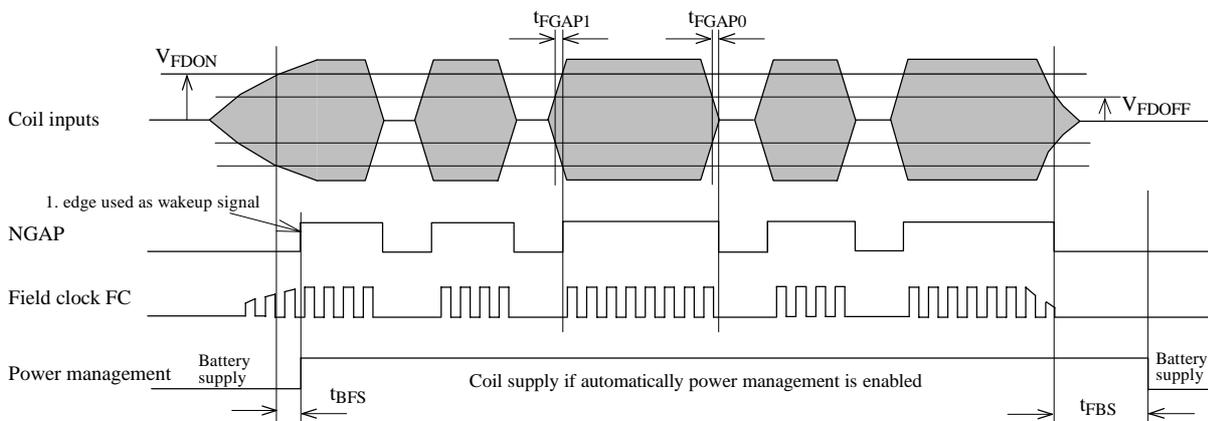


Figure 4. GAP and Modulation Timing

Digital output of the gap-detection stage (NGAP)

NGAP = 0: gap detected / no field

$$V_{\text{COIL_peak}} = V_{\text{FDoff}}$$

NGAP = 1: field detected

$$V_{\text{COIL_peak}} = V_{\text{FDOn}}$$

Note: No amplifier is used in the gap-detection stage. A digital Schmitt trigger evaluates the rectified and smoothed coil voltage.

1.6 Wake-up Signal

If a field is applied at the coil of the transponder interface the microcontroller can be woken up with the wake signal at the NGAP pin. For that purpose the NGAP pin must be connected to an interrupt input of the microcontroller. A high level at the NGAP output indicates an applied field and can be used as wake signal for the microcontroller via an interrupt. The wake signal is generated if the power

management switches to field supply. The field-detection stage of the power management has lowpass characteristics to avoid generating of wake signals and unnecessary switching between battery and field supply in case of interferences at the coil inputs.

1.7 Power Supply

The U9280M has a power management that handles two power supply sources. Normally the IC is supplied by a battery at the VBatt pin. If a magnetic field is applied at the LC-resonant circuit of the device the field detection circuit switches automatically from VBatt to field supply.

The VDD pin is used to connect a capacitor to smooth the voltage from the rectifier and to buffer the power while the field is modulated by gaps and damping. The EEPROM and the connected controller always operate with the voltage at the VDD pin.

Note: During field supply the maximum energy from the field is used if a high level is applied at the MOD input!

1.7.1 Automatic Power Management

There are different conditions to switch from the battery to field and back from field to the battery.

The power management switches from battery to field if the rectified voltage (V_{coil}) from the coil inputs becomes higher than the field-on-detection voltage (V_{FDOn}), even if no battery voltage is available ($0 < V_{Batt} < 1.8\text{ V}$). It switches back to battery if the coil voltage becomes lower than the field-off-detection voltage (V_{FDoff}).

The field detection stage of the power management has lowpass characteristics to suppress noise. An applied field needs a time delay t_{BFS} (battery-to-field switch delay) to change the power supply. If the field is removed from the coil, the power management will generate a reset that can be connected to the microcontroller.

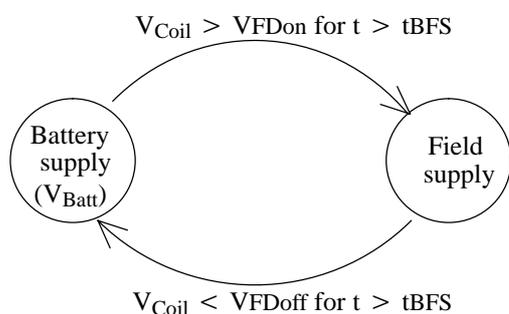


Figure 5. Switch conditions for the power management

Note: The rectified supply voltage from the coil is limited to V_{DDC} (2.9 V). During field supply the battery is switched off and V_{DD} changes to V_{DDC} .

1.7.2 Controlling the Power Management via the Serial Interface

The automatic mode of the power management can be switched off and on by a command from the microcontroller. If the automatic mode is switched off the IC is always supplied by the battery up to the next power-on reset or to a switch on command. The power management-on and -off command must be transferred via the serial interface.

If the power management is switched off and the device is supplied from the battery it can communicate via the field without load the field. This mode can be used to realize applications with battery supply if the field is too weak to supply the IC with power.

1.7.3 Buffer Capacitor C_B

The buffer capacitor connected at V_{DD} is used to buffer the supply voltage for the microcontroller and the EEPROM during field supply. It smoothes the rectified AC from the coil and buffers the supply voltage during modulation and gaps in the field.

The size of this capacitor depends on the application. It must be of a dimension so that during modulation and gaps the ripple on the supply voltage is in the range of 100 mV to 300 mV. During gaps and damping the capacitor is used to supply the device, that means the size of the capacitor depends on the length of the gaps and damping cycles.

Example: for a supply current 350 μA , 200 mV ripple @ V_{DD}

No Field Supply During	Necessary C_B
250 μs	470 nF
500 μs	1000 nF

1.8 Serial Interface

The transponder interface has an I²C like serial interface to the microcontroller for read and write accesses to the EEPROM. In a special mode the serial interface can also be used to control the Biphase/ Manchester modulator or the power management of the U3280M.

The serial interface of the U3280M device must be controlled by a master device (normally the microcontroller) which generates the serial clock and controls the access via the SCL and SDA line. SCL is used to clock the data in and out of the device. SDA is a bidirectional line and used to transfer data into and out of the device. The following protocol is used for the data transfers.

1.8.1 Serial Protocol

- Data states on the SDA line changing only during SCL is low.
- Changes in the SDA line while SCL is high will be interpreted as START or STOP condition.
- A STOP condition is defined as high-to-low transition on the SDA line while the SCL line is high.
- Each data transfer must be initialized with a START condition and terminated with a STOP condition. The START condition wakes the device from standby mode and the STOP condition returns the device to standby mode.
- A receiving device generates an acknowledge (A) after the reception of each byte. For that the master device must generate an extra clock pulse. If the reception was successful the receiving master or slave device pulls down the SDA line during that clock cycle. If in transmit mode an acknowledge is not detected (N) by the interface, it will terminate further data transmissions and will go into receive mode. A master device must finish its read operation by a not acknowledge and then issue a stop condition to place the device into a known state.

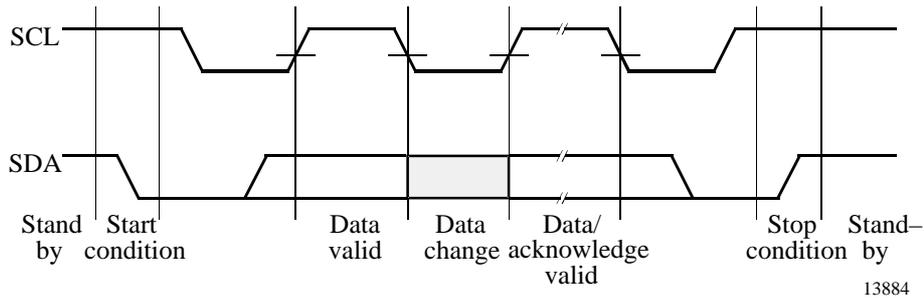


Figure 6. Serial protocol

Control Byte Format

	EEPROM address					Mode control bits		Read/NWrite	
Start	A4	A3	A2	A1	A0	C1	C0	R/NW	Ackn

The control byte follows the start condition and consists of the 5-bit row address, 2 mode control bits and the read/not write bit.

Data Transfer Sequence

Start	Control byte	Ackn	Data byte	Ackn	Data byte	Ackn	Stop
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- Before the start condition and after the stop condition the device is in standby mode and the SDA line is switched as input with pull-up resistor.
- The start condition follows a control byte that determines the following operation. Bit 0 of the control byte is used to control the following transfer direction. A "0" defines a write access and a "1" a read access.

1.9 EEPROM

The EEPROM has a size of 512 bit and is organized as 32 x 16 bit matrix. To read and write data to and from the EEPROM serial interface must be used. The interface supports one and two byte write accesses and one to n-byte read accesses to the EEPROM.

1.9.1 EEPROM – Operation Modes

The operating modes of the EEPROM are defined via the control byte. The control byte contains the row address, the mode control bits and the read/not-write bit, that is used to control the direction of the following transfer. A "0" defines a write access and a "1" a read access. The five address bits select one of the 32 rows of EEPROM memory to be accessed. For all accesses the complete 16-bit word of the selected row is loaded into a buffer. The buffer must be read or overwritten via the se-

rial interface. The two mode control bits C1 and C2 define in which order the accesses to the buffer are performed: High byte – low byte or low byte – high byte. The EEPROM supports also autoincrement and autodecrement read operations. After sending the start address with the corresponding mode consecutive memory cells can be read row by row without transmission of the row addresses.

Two special control bytes allow to initialize the complete EEPROM with "0" or with "1".

1.9.2 Write Operations

The EEPROM permits 8-bit and 16-bit write operations. A write access starts with the START condition followed by writing a write control byte and one or two data bytes from the master. It is complete with the STOP condition from the master after the acknowledge cycle.

If the EEPROM receives the control byte it loads the addressed memory cell into a 16-bit read/write buffer. The following data bytes overwrites the buffer. The internal EEPROM programming cycle is started by a stop condition after the first or second data byte. During the programming cycle the addressed EEPROM cells are cleared and the contents of the buffer is written back to the into the EEPROM cells. The complete erase-write cycle takes about 10 ms.

Acknowledge polling

If the EEPROM is busy with an internal write cycle all inputs are disabled and the EEPROM will not acknowledge until the write cycle is finished. This can be used to determine when the write cycle is complete. The master must perform acknowledge polling by sending a start condition

followed by the control byte. If the device is still busy with the write cycle, it will not return an acknowledge and the master has to generate a stop condition or perform further acknowledge polling sequences.

If the cycle is complete, it returns an acknowledge and the master can then proceed with the next read or write cycle.

Write One Data Byte

Start	Control byte	A	Data byte 1	A	Stop
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Write Two Data Bytes

Start	Control byte	A	Data byte 1	A	Data byte 2	A	Stop
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Write Control Byte Only

Start	Control byte	A	Stop
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A -> acknowledge

Write Control Bytes

Write low byte first

MSB					LSB		
A4	A3	A2	A1	A0	C1	C0	R/NW
Row address					0	1	0

Byte order

LB(R)	HB(R)
-------	-------

Write high byte first

MSB					LSB		
A4	A3	A2	A1	A0	C1	C0	R/NW
Row address					1	0	0

Byte order

HB(R)	LB(R)
-------	-------

HB: high byte; LB: low byte; R: row address

1.9.3 Read Operations

The EEPROM allows byte-, word- and current address read operations. The read operations are initiated in the same way as write operations. Every read access is initiated by sending the start condition followed by the control byte which contains the address and the read mode. After the device receives a read command it returns an acknowledge, loads the addressed word into the read/write buffer and sends the selected data byte to the master. The master has to acknowledge the received byte if it wants

to proceed the read operation. If two bytes are read out from the buffer the device increments respectively decrements the word address automatically and loads the buffer with the next word. The read mode bits determines if the low or high byte is read first from the buffer and if the word address is incremented or decremented for the next read access. If the memory address limit is reached, the data word address will "roll over" and the sequential read will continue. The master can terminate the read operation after every byte by not responding with an acknowledge (N) and by issuing a stop condition.

Read One Data Byte

Start	Control byte	A	Data byte 1	N	Stop
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Read Two Data Bytes

Start	Control byte	A	Data byte 1	A	Data byte 2	N	Stop
-------	--------------	---	-------------	---	-------------	---	------

Read n Data Bytes

Start	Control byte	A	Data byte 1	A	Data byte 2	A	-----	Data byte n	N	Stop
-------	--------------	---	-------------	---	-------------	---	-------	-------------	---	------

A → acknowledge, N → no acknowledge

Read Control Bytes

Read low byte first, address increment	MSB					LSB		
	A4	A3	A2	A1	A0	C1	C0	R/NW
	Row address					0	1	1

Byte order	LB(R)	HB(R)	LB(R+1)	HB(R+1)	---	LB(R+n)	HB(R+n)
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Read high byte first, addr. decrement	MSB					LSB		
	A4	A3	A2	A1	A0	C1	C0	R/NW
	Row address					1	0	1

Byte order	HB(R)	LB(R)	HB(R-1)	LB(R-1)	---	HB(R-n)	LB(R-n)
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HB: high byte; LB: low byte, R: row address

1.9.4 Initialization after a Reset Condition

The EEPROM with the serial interface has its own reset circuitry. In systems with microcontrollers that have their

own reset circuitry for power-on reset, watchdog reset or brown-out reset, it may be necessary to bring the U3280M into a known state independent on the internal reset. This is performed by reading one byte without acknowledging and then generating a stop condition.

1.10 Special Modes

Control Byte	Description
1100x111b	Biphase modulation
1101x111b	Manchester modulation
11xx0111b	Switch power management off → disables switching from battery to field supply
11xx1111b	Switch power management on → enables automatical switching between battery and field supply
xxxxx110b	Reserved

Data Transfer Sequence for Biphase and Manchester Modulation:

Start	Control byte	Ackn	Bit 1	Bit 2	Bit 3	Bit n	Stop
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With special control bytes the serial interface can be used to control the modulator stage or the power management. The EEPROM access and the serial interface are disabled in these modes until to the next stop condition. If no start or stop condition is generated the SCL and SDA line can be used for the modulator stage. SCL is used for the modulator clock and SDA is used for the data. In that mode the same conditions for clock and data changing like in the normal are valid. The SCL and SDA line can be used for continuous bit transfers, an acknowledge cycle after 8 bits must not be generated.

Note:

After a reset of the microcontroller it is not sure that the transponder interface has been reset too. It could still be in a receive or transmit cycle. To place the serial interface of the device into a known state the microcontroller should read one byte from the device without acknowledge and then generate a stop condition.

1.11 Power-On Reset, NRST

The U3280M transponder front end starts working with the applied field. For the digital circuits like EEPROM serial interface and registers there is a reset circuitry. A reset is generated by a power-on condition at VDD, by switching back from field to battery supply and if a low signal is applied at the NRST-pin.

The NRST-pin is a bidirectional pin and can also be used as reset output to generate a reset for the microcontroller if the circuit switches over from field to battery supply. This sets the microcontroller in a well defined state after the uncertain power supply condition during switching.

1.12 Antenna

For the transponder interface a coil must be used as antenna. Air and ferrite cored coils can be used. For battery-less operation the working distance resp. the minimum coupling factor of an application depends on the power consumption and on the size of the antennas of the IC and the base station. With a power consumption of 150 µA a minimum magnetic coupling factor below 0.5% is within reach. For applications with a higher power consumption the coupling factor must be increased.

The Q-factor of the antenna coil should be in the range between 30 to 80 for read only application and below 40 for bidirectional read-write applications.

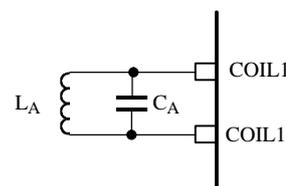
The antenna coil must be connected together with a capacitor as a parallel LC resonant circuit to the COIL1 and COIL2 pins of the IC. The resonance frequency f0 of the antenna circuit should be in the range of 100 to 150 kHz.

The right LC combination can be calculated with the following formula:

$$L_A = \frac{1}{C_A \times (2 \times \pi \times f_0)^2}$$

Note:

The coil input stage requires a minimum capacitor of 1.8 nF.



Example:

Antenna frequency: f0 = 125 kHz, capacitor: CA = 2.2 nF

$$\Rightarrow L_A = \frac{1}{2.2 \text{ nF} \times (2 \times \pi \times 125 \text{ kHz})^2} = 737 \mu\text{H}$$

2 Electrical Characteristics

2.1 Absolute Maximum Ratings

Voltages are given relative to V_{SS} .

Parameters	Symbol	Value	Unit
Supply voltage	V_{DD}, V_{Batt}	0 V to +7.0 V with reverse protection	V
Max. current out of V_{SS} pin		15	mA
Max. current into V_{Batt} pin		15	mA
Input voltage (on any pin)	V_{IN}	$V_{SS} - 0.6 \leq V_{IN} \leq V_{DD} + 0.6$	V
Input/output clamp current ($V_{SS} > V_i/V_o > V_{DD}$)	I_{IK} / I_{OK}	+/- 15	mA
Min. ESD protection (100pF through 1.5k Ω)		+/-2	kV
Operating-temperature range	T_{AMB}	- 40 to + 85	$^{\circ}C$
Storage-temperature range	T_{STG}	- 40 to + 125	$^{\circ}C$
Soldering temperature (t \leq 10 sec)	T_{SD}	260	$^{\circ}C$

Stresses greater than those listed under absolute maximum ratings may cause permanent damage to the device. This is a stress rating only and functional operation of the device at any condition above those indicated in the operational section of these specification is not implied. Exposure to absolute maximum rating condition for an extended period may affect device reliability. All inputs and outputs are protected against high electrostatic voltages or electric fields. However, precautions to minimize built-up of electrostatic charges during handling are recommended. Reliability of operation is enhanced if unused inputs are connected to an appropriate logic voltage level (e.g. V_{DD}).

2.2 DC Characteristics – Transponder Interface U3280M

Supply voltage $V_{DD} = 1.8$ to 6.5 V, $V_{SS} = 0$ V, $T_{amb} = -40^{\circ}C$ to $85^{\circ}C$ unless otherwise specified

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Power supply						
Operating voltage at V_{Batt}		V_{Batt}	2.0		6.5	V
Operating voltage at V_{DD} during battery supply		V_{DDB}		$V_{Batt} - V_{SD}$		V
V_{DD} -limiter voltage during coil supply		V_{DDC}	2.6	2.9	3.2	V
Operating current during field supply	$V_{DD} > 2.0$ V	I_{Fi}		40	80	μA
Sleep current		I_{SI}			0.4	μA
EEPROM						
Operating current during erase/write cycle	$V_{DD} = 2.0$ V	I_{WR}		400	500	μA
	$V_{DD} = 6.5$ V	I_{WR}			1200	μA
Operating current during read cycle *)	$V_{DD} = 2.0$ V	I_{Rdp}			300	μA
	$V_{DD} = 6.5$ V	I_{Rdp}			350	μA
Power management						
Field-on detection voltage	$V_{DD} > 1.8$ V	V_{FDon}	2.3	2.5	2.9	V
Field-off detection voltage	$V_{DD} > 1.8$ V	V_{FDOff}		0.8		V
Voltage drop at power-supply switch	$I_S = 0.5$ mA, $V_{Batt} = 2$ V	V_{SD}			150	mV

DC Characteristics – Transponder Interface U3280M(continued)

Supply voltage $V_{DD} = 1.8$ to 6.5 V, $V_{SS} = 0$ V, $T_{amb} = -40^{\circ}\text{C}$ to 85°C unless otherwise specified

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Coil inputs Coil 1 and Coil 2						
Coil input current		I_{CI}			20	mA
Input capacitance		C_{IN}	30			pF
Coil voltage stroke during modulation	$V_{CU} > 5\text{V}$ $I_{coil} = 3$ to 20 mA	V_{CMS}	1.8	2.3	4.0	V
Pin MOD						
Input LOW voltage		V_{IL}	V_{IH}		$0.2 V_{DD}$	V
Input LOW voltage		V_{IH}	$0.8V_{DD}$		V_{DD}	V
Input leakage current		$I_{leakage}$		10		nA
Pin NGAP/ FC						
Output LOW current	$V_{DD} = 2.0$ V $V_{OL} = 0.2 \times V_{DD}$	I_{OL}	0.08	0.2	0.3	mA
Output HIGH current	$V_{DD} = 2.0$ V $V_{OH} = 0.8 \times V_{DD}$	I_{OH}	-0.06	-0.15	-0.25	mA
Serial interface I/O pins SCL and SDA						
Input LOW voltage		V_{IL}	V_{IH}		$0.3 V_{DD}$	V
Input HIGH voltage		V_{IH}	$0.7 V_{DD}$		V_{DD}	V
Input leakage current		$I_{leakage}$		10		nA
Output LOW current	$V_{DD} = 2.0$ V $V_{OL} = 0.2 \times V_{DD}$ $V_{DD} = 6.0$ V	I_{OL}	0.7	0.9	1.1	mA
Output HIGH current	$V_{DD} = 2.0$ V $V_{OH} = 0.8 \times V_{DD}$ $V_{DD} = 6.0$ V	I_{OH}	-0.5	-0.6	-0.7	mA
			-1.8	-2.2	-2.6	mA

*) Peak current during 1/4 of read cycle

2.3 AC Characteristics – Transponder Interface U3280M

Supply voltage $V_{DD} = 1.8$ to 6.5 V, $V_{SS} = 0$ V, $T_{amb} = -40^{\circ}\text{C}$ to 85°C unless otherwise specified

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Serial interface timing						
SCL clock frequency		f_{SCL}	0		100	kHz
Clock low time		t_{LOW}	4.7			μs
Clock high time		t_{HIGH}	4.0			μs
SDA and SCL rise time		t_R			1000	ns
SDA and SCL fall time		t_F			300	ns
Start condition setup time		t_{SUSTA}	4.7			μs
Start condition hold time		t_{HDSTA}	4.0			μs
Data input setup time		t_{SUDAT}	250			ns
Data input hold time		t_{HDDAT}	0			ns
Stop condition setup time		t_{SUSTO}	4.7			μs
Bus free time		t_{BUF}	4.7			μs
Input filter time		t_f			100	ns
Data output hold time		t_{DH}	300		1000	ns

AC Characteristics – Transponder Interface U3280M (continued)

Supply voltage $V_{DD} = 1.8$ to 6.5 V, $V_{SS} = 0$ V, $T_{amb} = -40^{\circ}\text{C}$ to 85°C unless otherwise specified

Parameters	Test Conditions / Pins	Symbol	Min.	Typ.	Max.	Unit
Coil inputs						
Coil frequency		f_{COIL}	100	125	150	kHz
Gap detection						
Delay field off to GAP = 0	$V_{coilGap} < 0.7 V_{DC}$	T_{FGAP0}	10		50	μs
Delay field on to GAP = 1	$V_{coilGap} > 3 V_{DC}$	T_{FGAP1}	1		50	μs
Power management						
Battery to field switch delay		t_{BFS}			1000	μs
Field to battery switch delay	$V_{Batt} = 6.5$ V	t_{FBS}	5	10	30	ms
EEPROM						
Endurance	Erase/ write-cycles	E_D	500000			Cycles
Data erase/ write cycle time	For 16 bits access	t_{DEW}		9	12	ms
Data retention time	$T_{amb} = 25^{\circ}\text{C}$	t_{DR}	10			years
Power up to read operation		t_{PUR}			0.2	ms
Power up to write operation		t_{PUw}			0.2	ms
Reset						
Power-on reset	$V_{DDrise} = 0$ to 2 V	t_{rise}			10	ms
NRST	$V_{II} < 0.2 \times V_{DD}$	t_{res}	1			μs

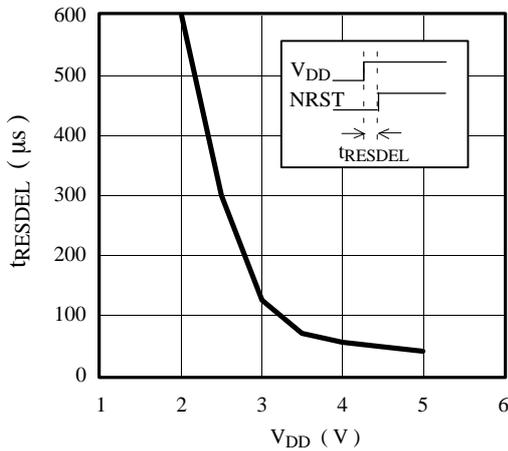


Figure 7. Typical reset delay after switching V_{DD} on

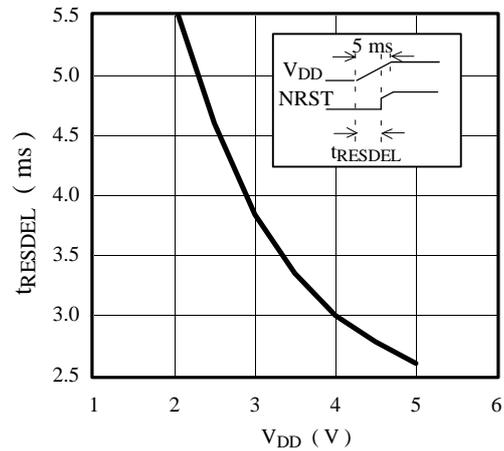


Figure 8. Typical reset delay after switching V_{DD} on

Ozone Depleting Substances Policy Statement

It is the policy of **TEMIC Semiconductor GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

TEMIC Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

TEMIC Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify TEMIC Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

Data sheets can also be retrieved from the Internet: <http://www.temic-semi.com>

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